

CD4023BM/CD4023BC **Buffered Triple 3-Input NAND Gate** CD4025BM/CD4025BC **Buffered Triple 3-Input NOR Gate**

General Description

These triple gates are monolithic complementary MOS (CMOS) integrated circuits constructed with N- and P-channel enhancement mode transistors. They have equal source and sink current capabilities and conform to standard B series output drive. The devices also have buffered outputs which improve transfer characteristics by providing very high gain. All inputs are protected against static discharge with diodes to VDD and VSS.

Features

■ Wide supply voltage range

3.0V to 15V

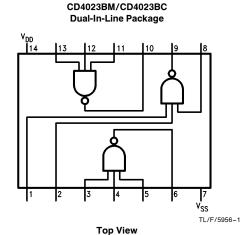
■ High noise immunity

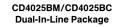
0.45 V_{DD} (typ.) fan out of 2 driving 74L

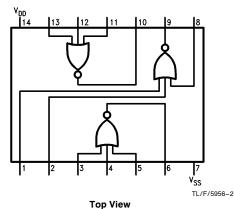
■ Low power TTL compatibility or 1 driving 74LS

- 5V-10V-15V parametric ratings
- Symmetrical output characteristics
- Maximum input leakage 1 µA at 15V over full temperature range

Connection Diagrams







Order Number CD4023B or CD4025B

Absolute Maximum Ratings (Notes 1 & 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

 $\begin{array}{ll} \text{DC Supply Voltage (V}_{\text{DD}}) & -0.5 \text{ V}_{\text{DC}} \text{ to } +18 \text{ V}_{\text{DC}} \\ \text{Input Voltage (V}_{\text{IN}}) & -0.5 \text{ V}_{\text{DC}} \text{ to V}_{\text{DD}} +0.5 \text{ V}_{\text{DC}} \\ \text{Storage Temp. Range (T}_{\text{S}}) & -65^{\circ}\text{C to } +150^{\circ}\text{C} \end{array}$

Power Dissipation (P_D)

 Dual-In-Line
 700 mW

 Small Outline
 500 mW

Lead Temperature (T_L) (Soldering, 10 seconds)

260°C

Recommended Operating Conditions

DC Supply Voltage (V_{DD}) 5 V_{DC} to 15 V_{DC} Input Voltage (V_{IN}) 0 V_{DC} to V_{DD} V_{DC}

Operating Temperature Range (T_A) CD4023BM, CD4025BM CD4023BC, CD4025BC

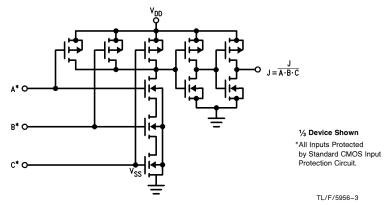
-55°C to +125°C -40°C to +85°C

DC Electrical Characteristics CD4023BM, CD4025BM (Note 2)

Symbol	Parameter	Conditions	-5	−55°C		+ 25°C		+ 125°C		Units
Symbol	rarameter	Conditions		Тур	Min	Тур	Max	Min	Мах	J.1113
I _{DD}	Quiescent Device Current	$egin{array}{lll} V_{DD} &= 5V \\ V_{DD} &= 10V \\ V_{DD} &= 15V \\ \end{array}$		0.25 0.5 1.0		0.004 0.005 0.006	0.25 0.5 1.0		7.5 15 30	μΑ μΑ μΑ
V _{OL}	Low Level Output Voltage	$V_{DD} = 5V \\ V_{DD} = 10V \\ V_{DD} = 15V$		0.05 0.05 0.05		0 0 0	0.05 0.05 0.05		0.05 0.05 0.05	V V V
V _{OH}	High Level Output Voltage	$egin{array}{ll} V_{DD} = 5V \ V_{DD} = 10V \ V_{DD} = 15V \end{array}$	4.95 9.95 14.95		4.95 9.95 14.95	5 10 15		4.95 9.95 14.95		V V
V _{IL}	Low Level Input Voltage	$ \begin{vmatrix} V_{DD} = 5V, \ V_O = 4.5V \\ V_{DD} = 10V, \ V_O = 9.0V \\ V_{DD} = 15V, \ V_O = 13.5V \end{vmatrix} I_O < 1\mu A $		1.5 3.0 4.0		2 4 6	1.5 3.0 4.0		1.5 3.0 4.0	V V
V _{IH}	High Level Input Voltage	$ \begin{vmatrix} V_{DD} = 5V, \ V_O = 0.5V \\ V_{DD} = 10V, \ V_O = 1.0V \\ V_{DD} = 15V, \ V_O = 1.5V \end{vmatrix} I_O < 1\mu A $	3.5 7.0 11.0		3.5 7.0 11.0	3 6 9		3.5 7.0 11.0		V V
l _{OL}	Low Level Output Current (Note 3)	$V_{DD} = 5V, V_{O} = 0.4V$ $V_{DD} = 10V, V_{O} = 0.5V$ $V_{DD} = 15V, V_{O} = 1.5V$	0.64 1.6 4.2		0.51 1.3 3.4	0.88 2.2 8		0.36 0.90 2.4		mA mA mA
ГОН	High Level Output Current (Note 3)	$V_{DD} = 5V, V_{O} = 4.6V$ $V_{DD} = 10V, V_{O} = 9.5V$ $V_{DD} = 15V, V_{O} = 13.5V$	-0.64 -1.6 -4.2		-0.51 -1.3 -3.4	-0.88 -2.2 -8		-0.36 -0.90 -2.4		mA mA mA
I _{IN}	Input Current	$V_{DD} = 15V, V_{IN} = 0V$ $V_{DD} = 15V, V_{IN} = 15V$		-0.10 0.10		-10 ⁻⁵	-0.10 0.10		-1.0 1.0	μA μA

Schematic Diagram

CD4023BC/CD4023BM



DC Electrical Characteristics CD4023BC, CD4025BC (Note 2)

Symbol	Parameter	Conditions		-40°C		+ 25°C			+85°C	
Зуппоот	raiailletei	Conditions	Min	Тур	Min	Тур	Max	Min	Max	Units
I _{DD}	Quiescent Device Current	$\begin{aligned} V_{DD} &= 5V \\ V_{DD} &= 10V \\ V_{DD} &= 15V \end{aligned}$		1.0 2.0 4.0		0.004 0.005 0.006	1.0 2.0 4.0		7.5 15 30	μΑ μΑ μΑ
V _{OL}	Low Level Output Voltage	$V_{DD} = 5V$ $V_{DD} = 10V$ $V_{DD} = 15V$		0.05 0.05 0.05		0 0 0	0.05 0.05 0.05		0.05 0.05 0.05	V V
V _{OH}	High Level Output Voltage	$V_{DD} = 5V$ $V_{DD} = 10V$ $V_{DD} = 15V$	4.95 9.95 14.95		4.95 9.95 14.95	5 10 15		4.95 9.95 14.95		V V
V _{IL}	Low Level Input Voltage	$ \begin{vmatrix} V_{DD}\!=\!5V,V_{O}\!=\!4.5V \\ V_{DD}\!=\!10V,V_{O}\!=\!9.0V \\ V_{DD}\!=\!15V,V_{O}\!=\!13.5V \end{vmatrix} I_{O} \!<\!1\mu A $		1.5 3.0 4.0		2 4 6	1.5 3.0 4.0		1.5 3.0 4.0	V V
V _{IH}	High Level Input Voltage	$ \begin{vmatrix} V_{DD}\!=\!5V,V_{O}\!=\!0.5V \\ V_{DD}\!=\!10V,V_{O}\!=\!1.0V \\ V_{DD}\!=\!15V,V_{O}\!=\!1.5V \end{vmatrix} \mid I_{O}\mid <1\mu A $	3.5 7.0 11.0		3.5 7.0 11.0	3 6 9		3.5 7.0 11.0		V V
loL	Low Level Output Current (Note 3)	$V_{DD} = 5V, V_{O} = 0.4V$ $V_{DD} = 10V, V_{O} = 0.5V$ $V_{DD} = 15V, V_{O} = 1.5V$	0.52 1.3 3.6		0.44 1.1 3.0	0.88 2.2 8		0.36 0.90 2.4		mA mA mA
Гон	High Level Output Current (Note 3)	$V_{DD} = 5V, V_{O} = 4.6V$ $V_{DD} = 10V, V_{O} = 9.5V$ $V_{DD} = 15V, V_{O} = 13.5V$	-0.52 -1.3 -3.6		-0.44 -1.1 -3.0	-0.88 -2.2 -8		-0.36 -0.90 -2.4		mA mA mA
I _{IN}	Input Current	$V_{DD} = 15V, V_{IN} = 0V$ $V_{DD} = 15V, V_{IN} = 15V$		-0.3 0.3		-10^{-5} 10^{-5}	-0.3 0.3		-1.0 1.0	μA μA

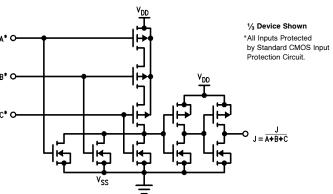
Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed; they are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.

Note 2: $V_{SS} = 0V$ unless otherwise specified.

Note 3: I_{OH} and I_{OL} are tested one output at a time.

Schematic Diagram

CD4025BM/CD4025BC



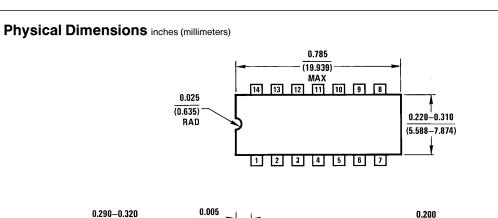
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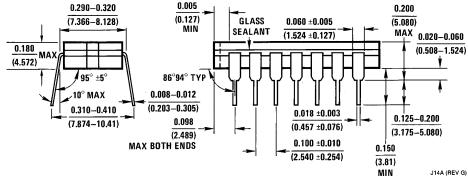
$\textbf{AC Electrical Characteristics*} \ \ \textbf{T}_{A} = 25^{\circ} \textbf{C}, \textbf{C}_{L} = 50 \ \textbf{pF}, \textbf{R}_{L} = 200 \textbf{k}, \textbf{unless otherwise specified}$

Symbol	Parameter	Conditions	CD4023BC CD4023BM			CD4025BC CD4025BM			Units
			Min	Тур	Max	Min	Тур	Max	
t _{PHL}	Propagation Delay, High-to-Low Level	$V_{DD} = 5V$ $V_{DD} = 10V$ $V_{DD} = 15V$		130 60 40	250 100 70		130 60 40	250 100 70	ns ns ns
t _{PLH}	Propagation Delay, Low-to-High Level	$V_{DD} = 5V$ $V_{DD} = 10V$ $V_{DD} = 15V$		110 50 35	250 100 70		120 60 40	250 100 70	ns ns ns
t _{THL} , t _{TLH}	Transition Time	$V_{DD} = 5V$ $V_{DD} = 10V$ $V_{DD} = 15V$		90 50 40	200 100 80		90 50 40	200 100 80	ns ns ns
C _{IN}	Average Input Capacitance	Any Input		5	7.5		5	7.5	pF
C_{PD}	Power Dissipation Capacity (Note 4)	Any Gate		17			17		pF

^{*}AC Parameters are guaranteed by DC correlated testing.

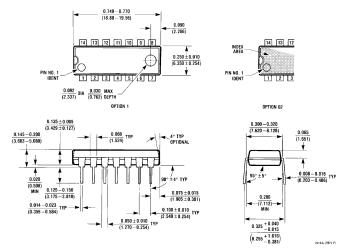
Note 4: C_{PD} determines the no load AC power consumption of any CMOS device. For complete explanation, see 54C/74C Family Characteristics Application Note AN-90.





Ceramic Dual-In-Line Package (J)
Order Number CD4023BMJ, CD4023BCJ, CD4025BMJ or CD4025BCJ
NS Package Number J14A

Physical Dimensions inches (millimeters) (Continued)



Molded Dual-In-Line Package (N) Order Number CD4023BMN, CD4023BCN, CD4025BMN or CD4025BCN NS Package Number N14A

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